LIST OF TABLES

Table 1.1:	Reduced mass μ , static dielectric constant ε_s , exciton binding energy E_B , and Bohr radius a_b of CdSe and ZnO (II-VI group semiconductor material).	6
Table 3.1:	Responsivity of the fabricated devices under the optical power density of 800 $\mu W/cm^2$ at 365 nm.	73
Table 4.1:	Measured values of n and k	87
Table 4.2:	Comparison among the other reported CdSe Schottky diodes at room temperature.	90
Table 4.3:	Comparison among other reported CdSe QDs based photodetectors or CdSe based self-powered photodetectors.	94
Table 5.1:	Comparison of device response/photoresponse between the other related hybrid self-powered photodetectors.	107
Table 6.1:	Comparison among the CdSe Schottky diodes with Au and Pd electrode at room temperature.	119
Table A.1:	Comparison among the Device A, B and C at room temperature	146

